



Revision 0.82

## **SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser**



## General Product Information

Product	Application
760 nm DFB Laser	Oxygen Detection
with hermetic 8 Pin TO Package	
including Monitor Diode, Thermoelectric Cooler and Thermistor	

EYP-DFB-0760-00040-1500-TOV01-0005



## Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	$T_S$	°C	-40		85
Operational Temperature at Case	$T_{C}$	°C	-20		75
Operational Temperature at Laser Chip	$T_{LD}$	°C	10		50
Forward Current	I <sub>F</sub>	mA			130
Reverse Voltage	$V_R$	V			2
Output Power	$P_{\text{opt}}$	mW			60
TEC Current	I <sub>TEC</sub>	Α			1.0
TEC Voltage	$V_{TEC}$	V			1.0

#### **Measurement Conditions / Comments**

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

#### Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	$T_{case}$	°C	-20		65
Operational Temperature at Laser Chip	$T_{LD}$	°C	10		35
Forward Current	I <sub>F</sub>	mA			120
Output Power	$P_{\text{opt}}$	mW	10		40

## Characteristics at T<sub>LD</sub> = 25° C at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm	759.9	760.9	761.9
Target Wavelength	$\lambda_{\text{T}}$	nm		760.9	
Linewidth (FWHM)	$\Delta\lambda$	MHz		2	
Sidemode Supression Ratio	SMSR	dB	30	50	
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06	
Current Coefficient of Wavelength	$d\lambda$ / $dI$	nm / mA		0.002	

ivieasurement Conditions / Comments
see images on page 4
reached within $T_{LD}$ = 10° and 35° C at 40 mW
$P_{opt} = 40 \text{ mW}$
$P_{opt} = 40 \text{ mW}$

## EYP-DFB-0760-00040-1500-TOV01-0005



Revision 0.82

## **SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser**





Characteristics at T <sub>LD</sub> = 25° C a	at BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	40		
Laser Current @ $P_{opt} = 40 \text{ mW}$	$I_{LD}$	mA			120
Slope Efficiency	η	W/A	0.6	8.0	1.3
Threshold Current	I <sub>th</sub>	mA			70
Divergence parallel (FWHM)	$\Theta_{  }$	0		8	
Divergence perpendicular (FWHM)	$\Theta_{\perp}$	0		21	
Degree of Polarization	DOP	%		90	

Measurement Conditions / Comments
at target wawevelength
parallel to Pin 1 - Pin 6 plane (see p. 3)
perpendicular to Pin 1 - Pin 6 plane (see p. 3)
P <sub>opt</sub> = 40 mW; E field perpendicular to Pin 1 - 6 plane

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I <sub>mon</sub> / P <sub>opt</sub>	μΑ/mW		2	

Meası	urement Conditions / Comments
$U_R =$	5 V

Thermoelectric Cooler					
Parameter	Symbol	Unit	min	typ	max
Current	I <sub>TEC</sub>	А		0.4	
Voltage	$U_TEC$	V		0.4	
Power Dissipation (total loss at case)	P <sub>loss</sub>	W		0.4	
Temperature Difference	ΔΤ	K			40

Meas	urement	Condi	tions /	Commei	nts	
P <sub>opt</sub> =	40 mW,	<b>Δ</b> T =	20 K			
P <sub>opt</sub> =	40 mW,	$\Delta T =$	20 K			
P <sub>opt</sub> =	40 mW,	$\Delta T =$	20 K			
P <sub>opt</sub> =	40 mW,	$\Delta T =$	Tcase	- TLD		

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3930	
Steinhart & Hart Coefficient A	А		1.029 x 10 <sup>-3</sup>		
Steinhart & Hart Coefficient B	В		2.510 x 10 <sup>-4</sup>		
Steinhart & Hart Coefficient C	C			1.051 x 10	-7

Measurement Conditions / Comments						
$T_{LD} = 25^{\circ} C$						
$R_1 / R_2 = e^{\beta (1/T_1 - 1/T_2)}$ at $T_{LD} =$	0° 50° C					
$1/T = A + B(\ln R) + C(\ln R)^3$						
T: temperature in Kelvin						
R: resistance at T in Ohm						

Thermistor (Standard NTC Type)

## EYP-DFB-0760-00040-1500-TOV01-0005



Revision 0.82

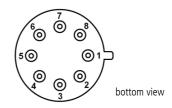
# **SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser**



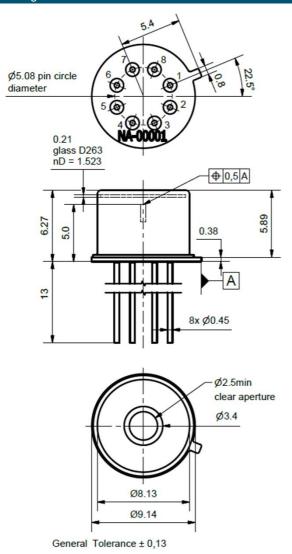


## Pin Assignment

1	Laser Diode Anode	5	Thermistor			
2	Laser Diode Cathode	6	Thermistor			
3	Thermoelectric Cooler (-)	7	Photo Diode Anode			
4	Thermoelectric Cooler (+)	8	Photo Diode Cathode			
All 8 pins are isolated from case.						



## Package Drawings



AIZ-19-0129-1426B

## EYP-DFB-0760-00040-1500-TOV01-0005



Revision 0.82

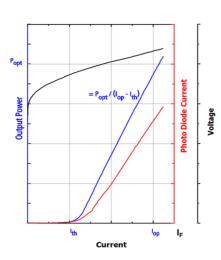
2020-04-30

## SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

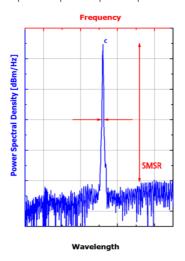


#### Typical Measurement Results

Output Power vs. Current



Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.





The DFB laser is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.



INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE
TO DIRECT OR SCATTERED RADIATION
CLASS 4 LASER PRODUCT
WAVELENGTH 760 nm
MAX. OUTPUT POWER 60 mW



